
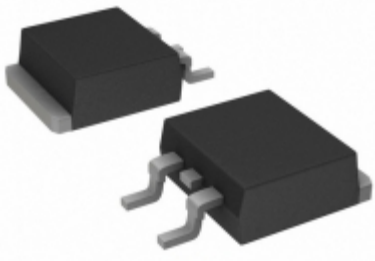
	<h2 style="color: red;">HGT1S7N60A4DS</h2> <p>Hersteller-Teilenummer: HGT1S7N60A4DS</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 34A 125W TO263AB</p> <p>Datenblätter:  HGT1S7N60A4DS.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4540 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	HGT1S7N60A4DS
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 600V 34A 125W TO263AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	4540 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	125W
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	TO-263AB
Rückwärts-Erholzeit (Trr)	34ns
Strom - Kollektor (Ic) (max)	34A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 7A
Strom - Collector Pulsed (Icm)	56A
Schaltenergie	55µJ (on), 60µJ (off)
Gate-Ladung	37nC
Td (ein / aus) bei 25 ° C	11ns/100ns
Testbedingung	390V, 7A, 25 Ohm, 15V
Verpackung	Tube
































HGT1S7N60A4DS ist neu im Original, Suche HGT1S7N60A4DS Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGT1S7N60A4DS Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage HGT1S7N60A4DS: Info@Y-IC.com

Sie können auch interessiert sein:

 HGT1S7N60A4DS AMI Semiconductor / ON Semiconductor IGBT 600V 34A 125W TO263AB	 HGT1S7N60B3 FAIRCHILD HGT1S7N60B3 FAIRCHILD	 HGT1S7N60A4S9A FAIRCHILD HGT1S7N60A4S9A FAIRCHILD	 HGT1S7N60A4DS.G7N60A4D fsc HGT1S7N60A4DS.G7N60A4D fsc
 HGT1S3N60A4DS9A AMI Semiconductor / ON Semiconductor IGBT 600V 17A 70W D2PAK	 HGT1S3N60A4DS9A Fairchild/ON Semiconductor IGBT 600V 17A 70W D2PAK	 HGT1S5N120CN Original HGT1S5N120CN Original	 HGT1S3N60C3DS9A INTERSIL HGT1S3N60C3DS9A INTERSIL

heiße Teile

Mehr

 HGT1S10N120BNST	 HGT1S10N120BNST	 HGT1S12N60C3	 HGT1S12N60C3DS	 HGT1S12N60C3DS9A
 HGT1S12N60C3S	 HGT1S14N40G3VLS	 D HGT1S14N41G3VL29A	 HGT1S14N41G3VLS9A	 HGT1S15N120C3ST
 HGT1S1N120CNDST	 HGT1S20N36G3VLS	 HGT1S20N36G3VLSR4737	 HGT1S20N60A4S9A	 HGT1S20N60A4S9A
 D HGT1S20N60C3R	 HGT1S20N60C3RS	 HGT1S2N120CN	 HGT1S2N120CN	 HGT1S3N60A4DS
 HGT1S3N60A4DS9A	 HGT1S3N60A4DS9A	 HGT1S3N60B3DS	 HGT1S3N60C3DS9A	 HGT1S7N60A4DS
 HGT1S7N60A4DS.G7N60A4D	 HGT1S7N60A4DS9A	 D HGT1S7N60A4S9A	 HGT1S7N60B3	 HGT1S7N60B3DS
 HGT1S7N60B3S	 D HGT1S7N60C3DS9A	 HGT1S7N60C3DS9A	 HGT1S7N60B3	 HGT1S7N60B3DS
 HGTG10N120BND	 HGTG10N120BND	 HGTG11N120CN	 HGTG11N120CN	 HGTG11N120CND
 HGTG11N120CND	 HGTG12N60A4	 HGTG12N60A4	 D HGTG12N60A4D	 HGTG12N60A4D
 HGTG12N60B3D	 HGTG12N60C3D	 HGTG12N60C3D	 HGTG18N120BN	 HGTG18N120BN

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